12500 TI Boulevard, MS 8640, Dallas, Texas 75243

PCN# 20230228004.1
Qualification of new Fab site (FFAB) using qualified Process Technology, Die Revision and additional Assembly site/BOM options for select devices
Change Notification / Sample Request

Date: March 07, 2023
To: TOKYO ELECTRON DEVICE (DSTR) PCN

Dear Customer:

This is an announcement of a change to a device that is currently offered by Texas Instruments (TI). The details of this change are on the following pages, and are in alignment with our standard product change notification (PCN) process.

TI requires acknowledgement of receipt of this notification within 30 days of the date of this notice. Lack of acknowledgement of this notice within 30 days constitutes acceptance of the change. If samples or additional data are required, requests must be received within 30 days of this notification, given that samples are not built ahead of the change.

The Proposed First Ship date in this PCN letter is the earliest possible date that customers could receive the changed material. It is our commitment that the changed device will not ship before that date. If samples are requested within the 30 day sample request window, customers will still have 30-days to complete their evaluation regardless of the proposed 1st ship date.

This particular PCN is related to TI's multiyear transition plan for our two remaining factories with 150-millimeter production (DFAB in Dallas, Texas, and SFAB in Sherman, Texas). DFAB will remain open, but will focus on 200-mm production, with a smaller set of technologies. SFAB will close no earlier than 2024 and no later than 2025. As referenced in the "reason for change" below, these changes are part of our multiyear plan to transition these products to newer, more efficient manufacturing processes and technologies, underscoring our commitment to product longevity and supply continuity.

For questions regarding this notice or to provide acknowledgement of this PCN, you may contact your local Field Sales Representative or the PCN Team (PCN_ww_admin_team@list.ti.com). For sample requests or sample related questions, contact your local Field Sales Representative. As always, we thank you for your continued business.

PCN Team
SC Business Services

20230228004.1
Attachment: 1

Products Affected:

The devices listed on this page are a subset of the complete list of affected devices. According to our records, these are the devices that you have purchased within the past twenty-four (24) months. The corresponding customer part number is also listed, if available.

DEVICE	CUSTOMER PART NUMBER
THS3095DDA	null

Technical details of this Product Change follow on the next page(s).

PCN Number:	20230228004.1	PCN Date:	March 07, 2023
Title:	Qualification of new Fab site (FFAB) using qualified Process Technology, Die Revision and additional Assembly site for select devices		
Customer Contact:	PCN Manager	Dept:	Quality Services
Proposed 1st Ship Date:	Jun 7, 2023	Sample requests accepted until:	Apr 7, 2023*

***Sample requests received after April 7, 2023 will not be supported.**

Change Type:					
☒	Assembly Site	☐	Assembly Process	☒	Assembly Materials
☒	Design	☐	Electrical Specification	☐	Mechanical Specification
☐	Test Site	☒	Packing/Shipping/Labeling	☐	Test Process
☐	Wafer Bump Site	☐	Wafer Bump Material	☐	Wafer Bump Process
☒	Wafer Fab Site	☒	Wafer Fab Materials	☒	Wafer Fab Process
		☐	Part number change		

PCN Details

Description of Change:

Texas Instruments is pleased to announce the qualification of a new fab & process technology (FFAB, BICOMHD) and additional Assembly site (FMX) for selected devices as listed below in the product affected section.

Current Fab Site			Additional Fab Site		
Current Fab Site	Process	Wafer Diameter	Additional Fab Site	Process	Wafer Diameter
DL-LIN	BICOM	150 mm	FFAB	BICOMHD	200 mm

The die was also changed as a result of the process change.

Construction differences are noted below:

	AMKOR P1	TI Mexico
Wire type	1.0 mil Au	1.0 mil Cu
Mount compound	101374994	4223772
Mold compound	101323396	4211880
Lead finish	Matte Sn	NiPdAu
MSL Level	1	2
Pin 1 marking	Stripe	Dimple

Upon expiry of this PCN TI will combine lead free solutions in a single ***standard part number***, for the devices in the "Product Affected" Section. For example; *THS3091DDAR* – can ship with both Matte Sn and NiPdAu.

Qual details are provided in the Qual Data Section.

Reason for Change:

These changes are part of our multiyear plan to transition products from our 150-millimeter factories to newer, more efficient manufacturing processes and technologies, underscoring our commitment to product longevity and supply continuity.

Anticipated impact on Form, Fit, Function, Quality or Reliability (positive / negative):

None

Impact on Environmental Ratings:

Checked boxes indicate the status of environmental ratings following implementation of this change. If below boxes are checked, there are no changes to the associated environmental ratings.

RoHS	REACH	Green Status	IEC 62474
☒ No Change	☒ No Change	☒ No Change	☒ No Change

Changes to product identification resulting from this PCN:

Fab Site Information:

Chip Site	Chip Site Origin Code (20L)	Chip Site Country Code (21L)	Chip Site City
DL-LIN	DLN	USA	Dallas
FR-BIP-1	**TID**	**DEU**	**Freising**

Die Rev:

Current	**New**
Die Rev [2P]	**Die Rev [2P]**
A	**A**

Assembly Site Information:

Assembly Site	Assembly Site Origin (22L)	Assembly Country Code (23L)	Assembly City
Amkor P1	AKR	PHL	Muntinlupa
TI Mexico	**MEX**	**MEX**	**Aguascalientes**

Sample product shipping label (not actual product label)

Product Affected:

THS3091DDA	THS3091DDAR	THS3095DDA	THS3095DDAR

For alternate parts with similar or improved performance, please visit the product page on TI.com

Qualification Report
Approve Date 22-SEPTEMBER-2022

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Type	#	Test Name	Condition	Duration	Qual Device: THS3095DDAR	QBS Process Reference: OPA2810IDGKR
HAST	A2	Biased HAST	130C/85%RH	96 Hours	3/230/0	3/231/0
UHAST	A3	Unbiased HAST	130C/85%RH	96 Hours	3/231/0	3/231/0
TC	A4	Temperature Cycle	-65C/150C	500 Cycles	3/231/0	3/231/0
HTSL	A6	High Temperature Storage Life	170C	420 Hours	3/231/0	3/231/0
HTOL	B1	Life Test	125C	1000 Hours	-	3/231/0
ELFR	B2	Early Life Failure Rate	125C	48 Hours	-	3/3000/0
ESD	E2	ESD CDM	-	1500 Volts	1/3/0	3/9/0
ESD	E2	ESD HBM	-	2500 Volts	1/3/0	3/9/0
LU	E4	Latch-Up	Per JESD78	-	1/3/0	3/9/0
CHAR	E5	Electrical Characterization	Per Datasheet Parameters	-	1/30/0	3/90/0

- QBS: Qual By Similarity
- Qual Device THS3095DDAR is qualified at MSL2 260C

- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable
- The following are equivalent HTOL options based on an activation energy of 0.7eV : 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours
- The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours
- The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

Green/Pb-free Status:

Qualified Pb-Free(SMT) and Green

For questions regarding this notice, e-mails can be sent to the contact below or your local Field Sales Representative.

Location	E-Mail
WW Change Management Team	PCN_ww_admin_team@list.ti.com